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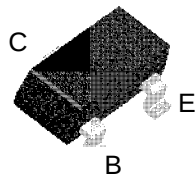
ON Semiconductor®

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FSB649



SuperSOT™-3

NPN Low Saturation Transistor

These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous. Sourced from Process NC.

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	FSB649	Units
V_{CEO}	Collector-Emitter Voltage	25	V
V_{CBO}	Collector-Base Voltage	35	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current - Continuous	3	A
T_J, T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150°C .
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Characteristic	Max	Units
		FSB649	
P_D	Total Device Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	250	$^\circ\text{C/W}$

NPN Low Saturation Transistor

(continued)

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHARACTERISTICS					
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10\text{ mA}$	25		V
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = 100\text{ }\mu\text{A}$	35		V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100\text{ }\mu\text{A}$	5		V
I_{CBO}	Collector Cutoff Current	$V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}, T_A = 100^\circ\text{C}$		100 10	nA μA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = 4\text{ V}$		100	nA
ON CHARACTERISTICS*					
h_{FE}	DC Current Gain	$I_C = 50\text{ mA}, V_{CE} = 2\text{ V}$ $I_C = 1\text{ A}, V_{CE} = 2\text{ V}$ $I_C = 2\text{ A}, V_{CE} = 2\text{ V}$ $I_C = 6\text{ A}, V_{CE} = 2\text{ V}$	70 100 75 15	300	-
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 1\text{ A}, I_B = 100\text{ mA}$ $I_C = 3\text{ A}, I_B = 300\text{ mA}$		300 600	mV
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 1\text{ A}, I_B = 100\text{ mA}$		1.25	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 1\text{ A}, V_{CE} = 2\text{ V}$		1	V
SMALL SIGNAL CHARACTERISTICS					
C_{obo}	Output Capacitance	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$		50	pF
f_T	Transition Frequency	$I_C = 100\text{ mA}, V_{CE} = 5\text{ V}, f = 100\text{ MHz}$	150		-

*Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2.0\%$

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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